# NSN 5961-00-995-4747

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-995-4747

Inclosure Material:

Metal

**Overall Length:** 

1.125 inches

# **Overall Diameter:**

1.063 inches

**Mounting Facility Quantity:** 

1

#### Internal Configuration:

Junction contact

#### **Mounting Method:**

Threaded stud

#### **Features Provided:**

Hermetically sealed case

#### **Overall Width Across Flats:**

1.219 inches

#### **Thread Size:**

0.500 inches

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 15.0

breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

10.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

250.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Thread Series Designator:**

Unf

# Terminal Type And Quantity:

1 tab, solder lug and 2 tab, solder lug

# **Specification Data:**

80131-release3577 professional/industrial association specification

# Shelf Life:

N/a

# Unit Of Measure:

---

#### Demilitarization:

No

# **NSN 5961-00-995-4747** Transistor - Page 2 of 2

Fiig: A110a0

